

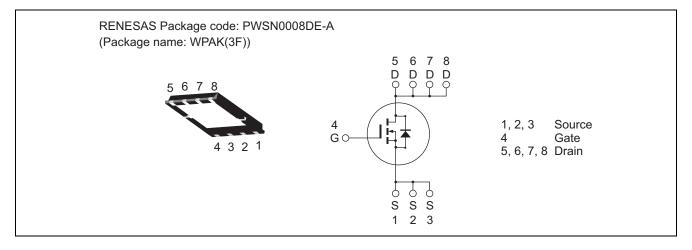
60V, 25A, 11.1mΩ max. N Channel Power MOS FET High Speed Power Switching

R07DS0344EJ0300 Rev.3.00 Apr 09, 2013

## Features

- High speed switching
- Low drive current
- High density mounting
- Low on-resistance
- Pb-free
- Halogen-free

#### Outline



## **Absolute Maximum Ratings**

			$(Ta = 25^{\circ}C)$
Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	60	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	I <sub>D</sub> 25		A
Drain peak current	I <sub>D(pulse)</sub> Note1	100	A
Body-drain diode reverse drain current	I <sub>DR</sub>	25	А
Avalanche current	I <sub>AP</sub> Note 2	12.5	А
Avalanche energy	E <sub>AS</sub> Note 2	11.7	mJ
Channel dissipation	Pch Note3	50	W
Channel to case thermal impedance	θch-c <sup>Note3</sup>	2.5	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1.  $PW \leq 10~\mu s,~duty~cycle \leq 1\%$ 

2. Value at Tch = 25°C, Rg  $\geq$  50  $\Omega$ 

3. Tc = 25°C



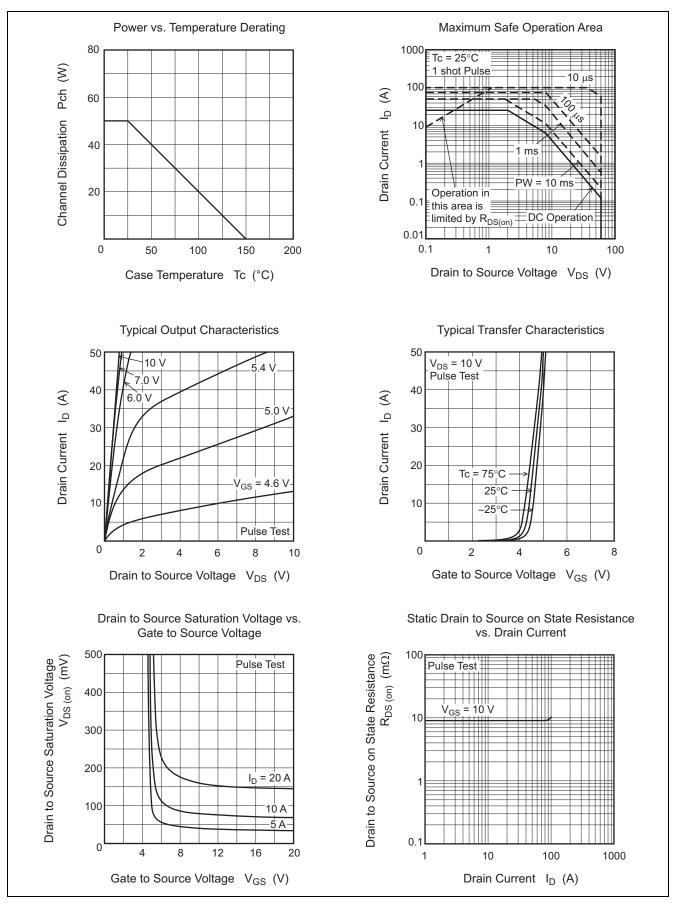
## **Electrical Characteristics**

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	60	—		V	$I_{D}$ = 10 mA, $V_{GS}$ = 0 V
Gate to source leak current	I <sub>GSS</sub>	—	—	±0.1	μA	$V_{GS}$ = ±20 V, $V_{DS}$ = 0 V
Zero gate voltage drain current	I <sub>DSS</sub>	_	—	1	μA	$V_{DS}$ = 60 V, $V_{GS}$ = 0 V
Gate to source cutoff voltage	V <sub>GS(off)</sub>	2.0	—	4.0	V	$V_{DS}$ = 10 V, $I_{D}$ = 1 mA
Static drain to source on state resistance	R <sub>DS(on)</sub>	_	9.0	11.1	mΩ	$I_D$ = 12.5 A, $V_{GS}$ = 10 V <sup>Note4</sup>
Forward transfer admittance	y <sub>fs</sub>	_	36		S	$I_D$ = 12.5 A, $V_{DS}$ = 10 V <sup>Note4</sup>
Input capacitance	Ciss	_	1580		pF	$V_{DS}$ = 10 V, $V_{GS}$ = 0 V,
Output capacitance	Coss	_	360		pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	100		pF	
Gate Resistance	Rg	_	2.7		Ω	
Total gate charge	Qg	—	19.4	_	nC	$V_{DD}$ = 25 V, $V_{GS}$ = 10 V, I <sub>D</sub> = 25 A
Gate to source charge	Qgs	_	8		nC	
Gate to drain charge	Qgd	_	3.2		nC	
Turn-on delay time	t <sub>d(on)</sub>	—	12		ns	$V_{GS}$ = 10 V, $I_{D}$ = 12.5 A,
Rise time	tr	_	11		ns	$V_{\text{DD}} \cong 30 \text{ V}, \text{ R}_{\text{L}} = 2.4 \Omega,$ Rg = 4.7 $\Omega$
Turn-off delay time	t <sub>d(off)</sub>	_	36		ns	
Fall time	t <sub>f</sub>	—	9.5		ns	
Body-drain diode forward voltage	V <sub>DF</sub>		0.8	1.1	V	$I_F = 25 \text{ A}, V_{GS} = 0 \text{ V}^{\text{Note4}}$
Body-drain diode reverse recovery time	t <sub>rr</sub>		35		ns	I <sub>F</sub> = 25 A, V <sub>GS</sub> = 0 V
						di <sub>F</sub> / dt = 100 A/ μs

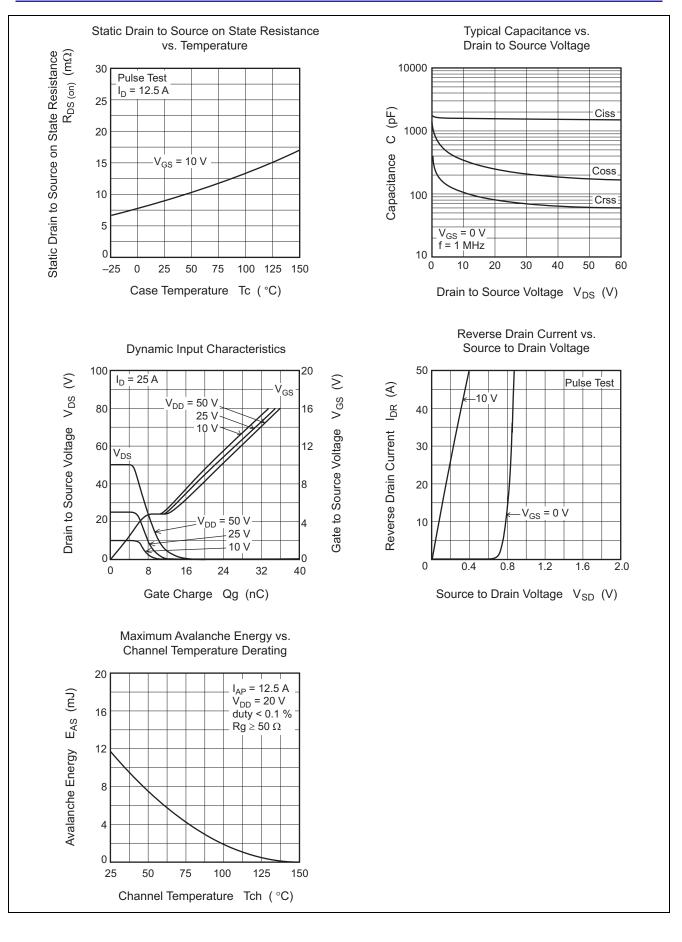
Notes: 4. Pulse test



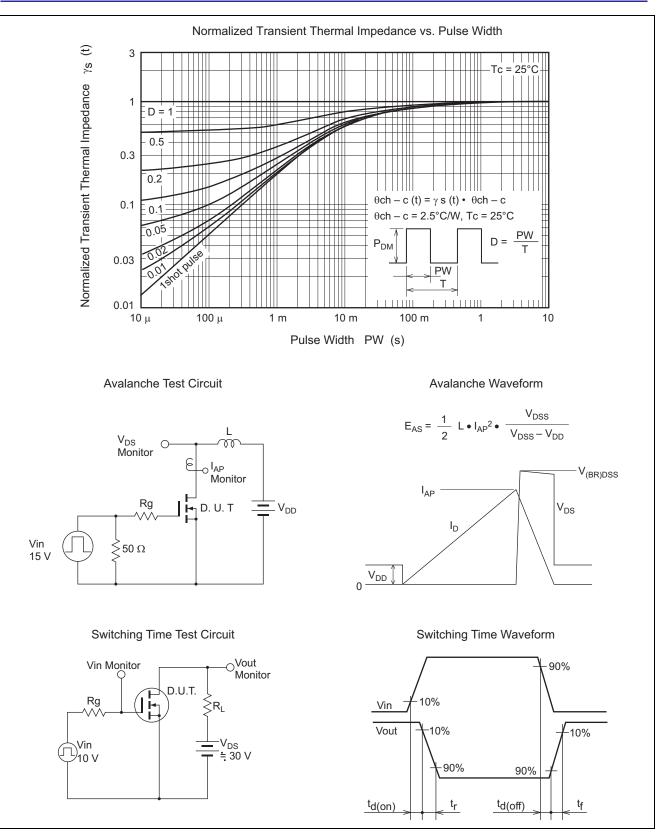
#### **Main Characteristics**





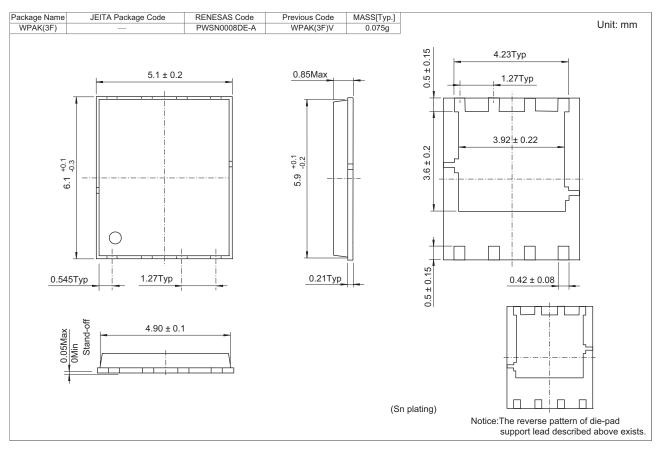








## **Package Dimensions**



## **Ordering Information**

Orderable Part No.	Quantity	Shipping Container
RJK0658DPA-00-J5A	3000 pcs	Taping

Note: The symbol of 2nd "-" is occasionally presented as "#".



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Renesas Electronics Europe Limited

Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K

Tel: +44-1628-651-700, Fax: +444-1628-651-804

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Disseldorf, Germany

Tel: +49-211-65030, Fax: +449-211-6503-1327

Renesas Electronics (Shanghal) Co., Ltd.

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